

ZENER DIODES

RD2.0FM to RD120FM

ZENER DIODES 1 W 2 PIN POWER MINI MOLD

DESCRIPTION

Type RD2.0FM to RD120FM series are 2 pin power mini mold package zener diodes possessing an allowable power dissipation of 1 W.

QUALITY GRADE

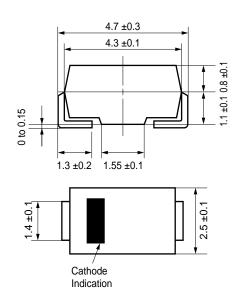
Standard.

Please refer to "Quality Grades On NEC Semiconductor Devices" (Document number C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

FEATURES

- · Sharp breakdown characteristics
- Vz: Applied E24 standard

PACKAGE DIMENSIONS (Unit: mm)



APPLICATIONS

Circuits for, constant voltage, constant current, waveform clipper, surge absorber, etc.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

| Power Dissipation | Р | 1 | W |
|----------------------|---------|-------------|----|
| Forward Current | lF | 200 | mΑ |
| Junction Temperature | T_{j} | 150 | °C |
| Storage Temperature | Tstg | -55 to +150 | °C |

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ELECTRICAL CHARACTERISTICS (TA = 25 ±2°C)

(1/2)

| Type Number Class | Class | | Zener Voltage Vz (V) Note1 | Dynamic Im Zz (Ω) | | 1. | Reverse Current IR (μ A) | |
|-------------------|-------|------|-------------------------------|----------------------|------|---------|-------------------------------|--------|
| | | MIN. | MAX. | Iz (mA) | MAX. | Iz (mA) | MAX. | VR (V) |
| RD2.0FM | В | 1.9 | 2.2 | 5 | 140 | 5 | 200 | 0.5 |
| RD2.2FM | В | 2.1 | 2.4 | 5 | 140 | 5 | 200 | 0.7 |
| RD2.4FM | В | 2.3 | 2.6 | 5 | 140 | 5 | 200 | 1.0 |
| RD2.7FM | В | 2.5 | 2.9 | 5 | 140 | 5 | 150 | 1.0 |
| RD3.0FM | В | 2.8 | 3.2 | 5 | 140 | 5 | 100 | 1.0 |
| RD3.3FM | В | 3.1 | 3.5 | 5 | 140 | 5 | 80 | 1.0 |
| RD3.6FM | В | 3.4 | 3.8 | 5 | 140 | 5 | 60 | 1.0 |
| RD3.9FM | В | 3.7 | 4.1 | 5 | 140 | 5 | 40 | 1.0 |
| RD4.3FM | В | 4.0 | 4.5 | 5 | 140 | 5 | 20 | 1.0 |
| RD4.7FM | В | 4.4 | 4.9 | 5 | 100 | 5 | 20 | 1.0 |
| RD5.1FM | В | 4.8 | 5.4 | 5 | 100 | 5 | 20 | 1.0 |
| RD5.6FM | В | 5.3 | 6.0 | 5 | 70 | 5 | 20 | 1.5 |
| RD6.2FM | В | 5.8 | 6.6 | 5 | 40 | 5 | 20 | 3.0 |
| RD6.8FM | В | 6.4 | 7.2 | 5 | 25 | 5 | 20 | 3.5 |
| RD7.5FM | В | 7.0 | 7.9 | 5 | 25 | 5 | 20 | 4.0 |
| RD8.2FM | В | 7.7 | 8.7 | 5 | 25 | 5 | 20 | 5.0 |
| RD9.1FM | В | 8.5 | 9.6 | 5 | 25 | 5 | 20 | 6.0 |
| RD10FM | В | 9.4 | 10.6 | 5 | 20 | 5 | 10 | 7.0 |
| RD11FM | В | 10.4 | 11.6 | 5 | 20 | 5 | 10 | 8.0 |
| RD12FM | В | 11.4 | 12.6 | 5 | 25 | 5 | 10 | 9.0 |
| RD13FM | В | 12.4 | 14.1 | 5 | 30 | 5 | 10 | 10 |
| RD15FM | В | 13.8 | 15.6 | 5 | 30 | 5 | 10 | 11 |
| RD16FM | В | 15.3 | 17.1 | 5 | 40 | 5 | 10 | 12 |
| RD18FM | В | 16.8 | 19.1 | 5 | 45 | 5 | 10 | 13 |
| RD20FM | В | 18.8 | 21.2 | 5 | 55 | 5 | 10 | 15 |
| RD22FM | В | 20.8 | 23.3 | 2 | 55 | 2 | 10 | 17 |
| RD24FM | В | 22.8 | 25.6 | 2 | 70 | 2 | 10 | 19 |
| RD27FM | В | 25.1 | 28.9 | 2 | 80 | 2 | 10 | 21 |
| RD30FM | В | 28.0 | 32.0 | 2 | 80 | 2 | 10 | 23 |
| RD33FM | В | 31.0 | 35.0 | 2 | 80 | 2 | 10 | 25 |
| RD36FM | В | 34.0 | 38.0 | 2 | 90 | 2 | 10 | 27 |
| RD39FM | В | 37.0 | 41.0 | 2 | 130 | 2 | 10 | 30 |
| RD43FM | В | 40.0 | 45.0 | 2 | 150 | 2 | 5 | 33 |
| RD47FM | В | 44.0 | 49.0 | 2 | 170 | 2 | 5 | 36 |
| RD51FM | В | 48.0 | 54.0 | 2 | 220 | 2 | 5 | 39 |
| RD56FM | В | 53.0 | 60.0 | 2 | 220 | 2 | 5 | 43 |
| RD62FM | В | 58.0 | 66.0 | 2 | 220 | 2 | 5 | 47 |
| RD68FM | В | 64.0 | 72.0 | 2 | 230 | 2 | 5 | 52 |

Note 1. Vz is tested with pulsed (40 ms).

2. Zz is measured at Iz by given a very small A.C. signal.

ELECTRICAL CHARACTERISTICS (TA = 25 ±2°C)

| Type Number | Class | Zener Voltage Vz (V) ^{Note1} | | Dynamic Impedance Zz (Ω) ^{Note2} | | Reverse Current Ir (µA) | | |
|-------------|-------|--|-------|--|------|----------------------------|------|--------------------|
| | | MIN. | MAX. | Iz (mA) | MAX. | Iz (mA) | MAX. | V _R (V) |
| RD75FM | В | 70.0 | 79.0 | 2 | 250 | 2 | 5 | 57 |
| RD82FM | В | 77.0 | 87.0 | 2 | 270 | 2 | 5 | 63 |
| RD91FM | В | 85.0 | 96.0 | 2 | 340 | 2 | 5 | 69 |
| RD100FM | В | 94.0 | 106.0 | 2 | 430 | 2 | 5 | 76 |
| RD110FM | В | 104.0 | 116.0 | 2 | 530 | 2 | 5 | 84 |
| RD120FM | В | 114.0 | 126.0 | 2 | 620 | 2 | 5 | 91 |

Note 1. Vz is tested with pulsed (40 ms).

^{2.} Zz is measured at Iz by given a very small A.C. signal.

TYPICAL CHARACTERISTICS (T_A = 25°C)



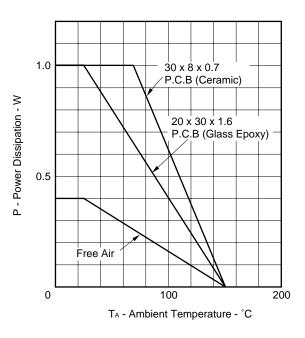
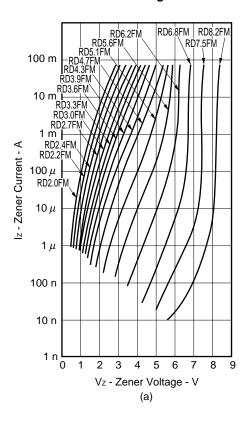
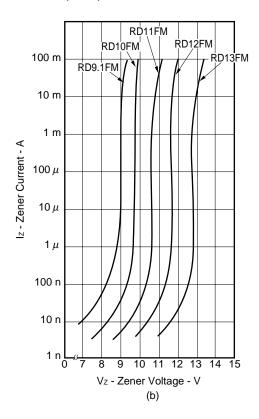
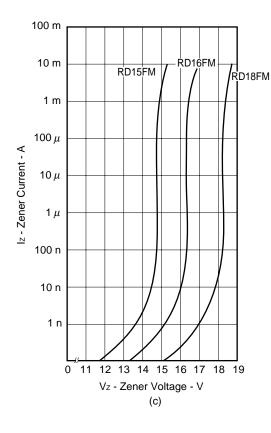
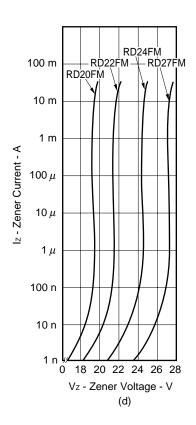


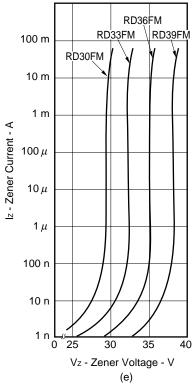
Fig.2 Iz - Vz CHARACTERISTICS (a to f)

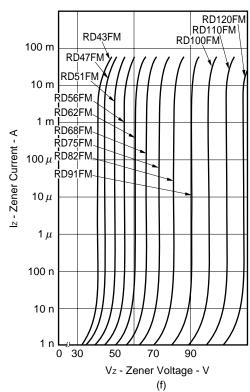












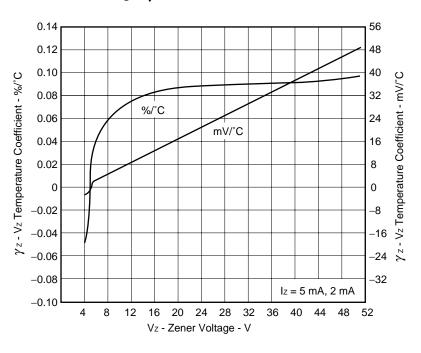


Fig.3 γ z - Vz CHARACTERISTICS

Fig.4 Zz - Iz CHARACTERISTICS

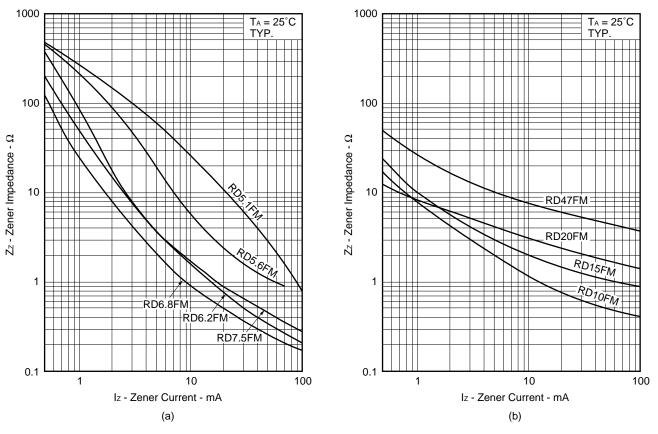


Fig.5 TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS

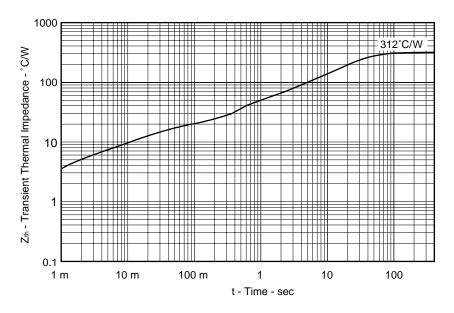
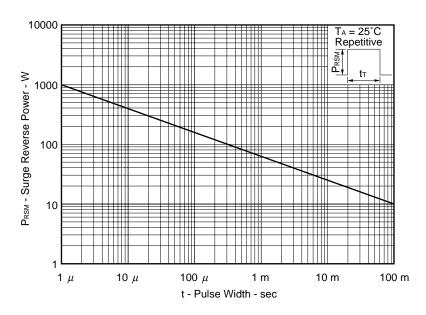


Fig.6 SURGE REVERSE POWER RATINGS



Data Sheet D16083EJ1V0DS 7

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